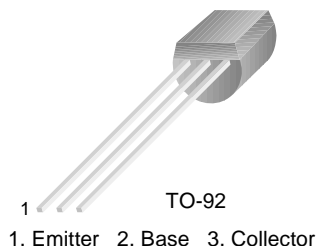


# KSP92/93

KSP92/93

## High Voltage Transistor



## PNP Epitaxial Silicon Transistor

### Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol    | Parameter                                              | Value     | Units                |
|-----------|--------------------------------------------------------|-----------|----------------------|
| $V_{CBO}$ | Collector-Base Voltage<br>: KSP92<br>: KSP93           | -300      | V                    |
|           |                                                        | -200      | V                    |
| $V_{CEO}$ | Collector-Emitter Voltage<br>: KSP92<br>: KSP93        | -300      | V                    |
|           |                                                        | -200      | V                    |
| $V_{EBO}$ | Emitter-Base Voltage                                   | -5        | V                    |
| $I_C$     | Collector Current                                      | -500      | mA                   |
| $P_C$     | Collector Power Dissipation ( $T_a=25^\circ\text{C}$ ) | 625       | mW                   |
|           | Derate above $25^\circ\text{C}$                        | 5         | mW/ $^\circ\text{C}$ |
| $P_C$     | Collector Power Dissipation ( $T_C=25^\circ\text{C}$ ) | 1.5       | W                    |
|           | Derate above $25^\circ\text{C}$                        | 12        | mW/ $^\circ\text{C}$ |
| $T_J$     | Junction Temperature                                   | 150       | $^\circ\text{C}$     |
| $T_{STG}$ | Storage Temperature                                    | -55 ~ 150 | $^\circ\text{C}$     |

### Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

| Symbol               | Parameter                                                   | Test Condition                                                                                                                        | Min. | Max.  | Units         |
|----------------------|-------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------|------|-------|---------------|
| $BV_{CBO}$           | Collector-Base Breakdown Voltage<br>: KSP92<br>: KSP93      | $I_C = -100\mu\text{A}, I_E = 0$                                                                                                      | -300 |       | V             |
|                      |                                                             |                                                                                                                                       | -200 |       | V             |
| $BV_{CEO}$           | * Collector-Emitter Breakdown Voltage<br>: KSP92<br>: KSP93 | $I_C = -1\text{mA}, I_B = 0$                                                                                                          | -300 |       | V             |
|                      |                                                             |                                                                                                                                       | -200 |       | V             |
| $BV_{EBO}$           | Emitter-Base Breakdown Voltage                              | $I_E = -100\mu\text{A}, I_C = 0$                                                                                                      | -5   |       | V             |
| $I_{CBO}$            | Collector Cur-off Current<br>: KSP92<br>: KSP93             | $V_{CB} = -200\text{V}, I_E = 0$<br>$V_{CB} = -160\text{V}, I_E = 0$                                                                  |      | -0.25 | $\mu\text{A}$ |
|                      |                                                             |                                                                                                                                       |      | -0.25 | $\mu\text{A}$ |
| $I_{EBO}$            | Emitter Cut-off Current                                     | $V_{EB} = -3\text{V}, I_C = 0$                                                                                                        |      | -0.10 | $\mu\text{A}$ |
| $h_{FE}$             | * DC Current Gain                                           | $V_{CE} = -10\text{V}, I_C = -1\text{mA}$<br>$V_{CE} = -10\text{V}, I_C = -10\text{mA}$<br>$V_{CE} = -10\text{V}, I_C = -30\text{mA}$ | 25   |       |               |
|                      |                                                             |                                                                                                                                       | 40   |       |               |
|                      |                                                             |                                                                                                                                       | 25   |       |               |
| $V_{CE}(\text{sat})$ | *Collector-Emitter Saturation Voltage                       | $I_C = -20\text{mA}, I_B = -2\text{mA}$                                                                                               |      | -0.50 | V             |
| $V_{BE}(\text{sat})$ | * Base-Emitter Saturation Voltage                           | $I_C = -20\text{mA}, I_B = -2\text{mA}$                                                                                               |      | -0.90 | V             |
| $f_T$                | Current Gain Bandwidth Product                              | $V_{CE} = -20\text{V}, I_C = -10\text{mA}, f = 100\text{MHz}$                                                                         | 50   |       | MHz           |
| $C_{ob}$             | Output Capacitance<br>: KSP92<br>: KSP93                    | $V_{CB} = -20\text{V}, I_E = 0$<br>$f = 1\text{MHz}$                                                                                  |      | 6     | pF            |
|                      |                                                             |                                                                                                                                       |      | 8     | pF            |

\* Pulse Test:  $PW \leq 300\mu\text{s}$ , Duty Cycles  $\leq 2\%$

# Typical Characteristics

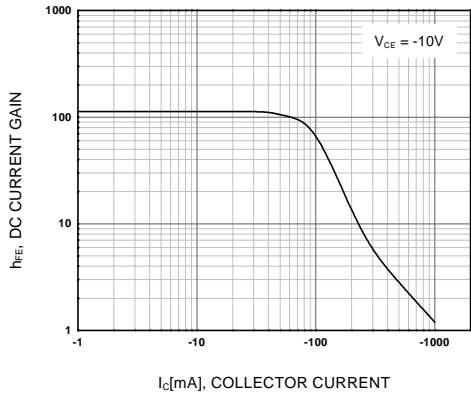


Figure 1. DC current Gain

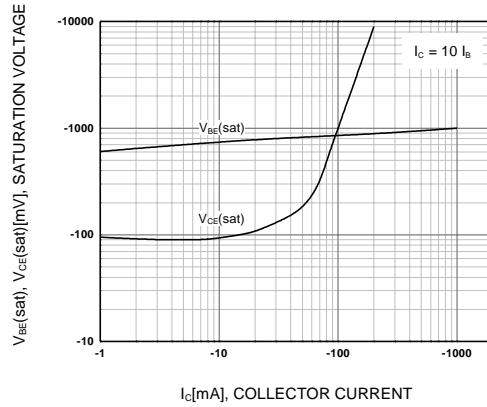


Figure 2. Saturation Voltage

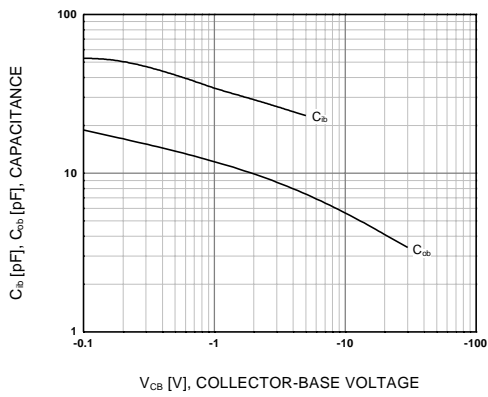


Figure 3. Capacitance

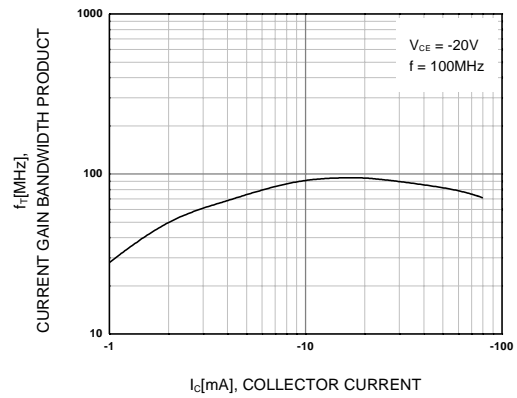


Figure 4. Current Gain Bandwidth Product

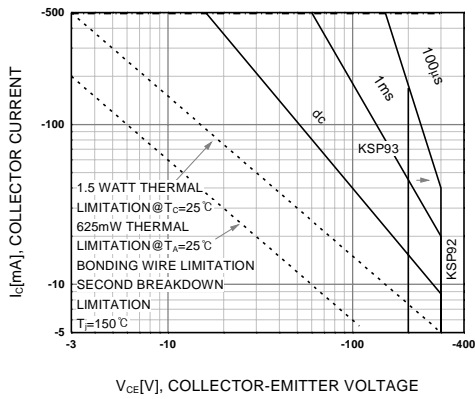


Figure 5. Active-Region Safe Operating Area

# Package Dimensions

KSP92/93

## TO-92



Dimensions in Millimeters

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### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331